



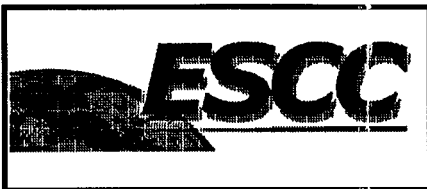
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**DIODES, POWER RECTIFIER,  
HIGH EFFICIENCY, FAST RECOVERY,  
BASED ON TYPE BYV54-200  
ESCC Detail Specification No. 5103/031**

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DCR No.	CHANGE DESCRIPTION
53	Specification up-issued to incorporate editorial and technical changes per DCR.

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**1. GENERAL**

**1.1 SCOPE**

This specification details the ratings, physical and electrical characteristics, test and inspection data for Diodes, Power Rectifier, High Efficiency, based on Type BYV54-200. It shall be read in conjunction with ESCC Generic Specification No.5000, the requirements of which are supplemented herein.

**1.2 COMPONENT TYPE VARIANTS**

Variants of the basic type diodes specified herein, which are also covered by this specification, are given in Table 1(a).

**1.3 MAXIMUM RATINGS**

The maximum ratings, which shall not be exceeded at any time during use or storage, applicable to the diodes specified herein, are as scheduled in Table 1(b).

**1.4 PARAMETER DERATING INFORMATION**

The derating information applicable to the diodes specified herein is shown in Figure 1.

**1.5 PHYSICAL DIMENSIONS**

The physical dimensions of the diodes specified herein are shown in Figure 2.

**1.6 FUNCTIONAL DIAGRAM**

The functional diagram, showing terminal identification of the diodes specified herein, is shown in Figure 3.

**1.7 HIGH TEMPERATURE TEST PRECAUTIONS**

For tin-lead plated or solder-dipped lead finish, all tests to be performed at a temperature that exceeds +125°C shall be carried out in a 100% inert atmosphere.

**1.8 HANDLING PRECAUTIONS**

These devices are susceptible to damage by electrostatic discharge. Therefore, suitable precautions shall be employed for protection during all phases of manufacture, testing, packaging, shipment and any handling.

**2. APPLICABLE DOCUMENTS**


The following documents form part of this specification and shall be read in conjunction with it:-

- (a) ESCC Generic Specification No. 5000 for Discrete Semiconductors.
- (b) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices.

**3. TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS**

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESCC Basic Specification No. 21300 shall apply. In addition, the following abbreviation is used:-

$C_J$  = Junction Capacitance.

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**TABLE 1(a) - TYPE VARIANTS**

VARIANT	BASED ON TYPE	CASE	FIGURE	LEAD MATERIAL AND FINISH
01	BYV54-200FSY	TO254	2	H9

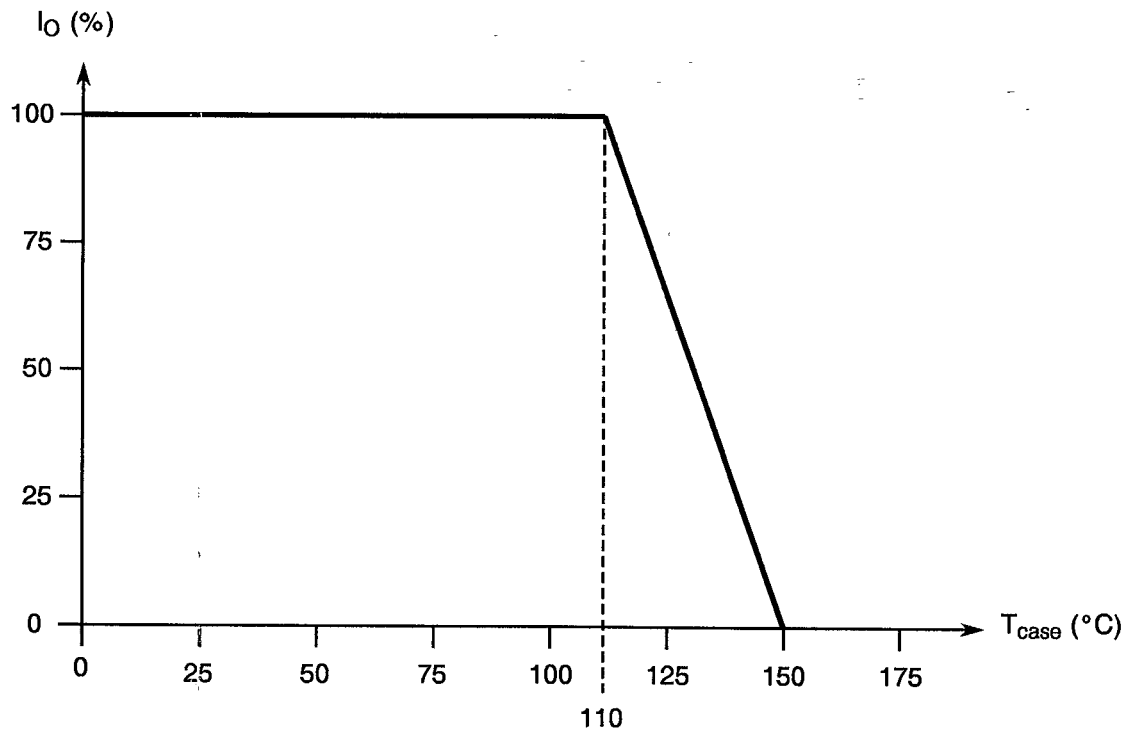
**TABLE 1(b) - MAXIMUM RATINGS**

No.	CHARACTERISTICS	SYMBOL	MAXIMUM RATINGS	UNIT	REMARKS
1	Forward Surge Current	$I_{FSM}$	400	A	Note 1
2	Repetitive Peak Reverse Voltage	$V_{RRM}$	200	V	
3	Average Output Rectified Current	$I_O$	40	A	Note 2
4	RMS Forward Current	$I_{F(RMS)}$	60	A	
5	Junction Temperature	$T_J$	+ 150	°C	
6	Storage Temperature Range	$T_{stg}$	- 55 to + 150	°C	
7	Soldering Temperature	$T_{sol}$	+ 260	°C	Note 3
8	Thermal Resistance (Junction to Case)	$R_{TH(J-C)}$	1.0	°C/W	

**NOTES**

1. Sinusoidal, with period = 10ms.
2. At  $T_{case} \leq +110^{\circ}C$ . For derating at  $T_{case} > +110^{\circ}C$ , see Figure 1.
3. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.

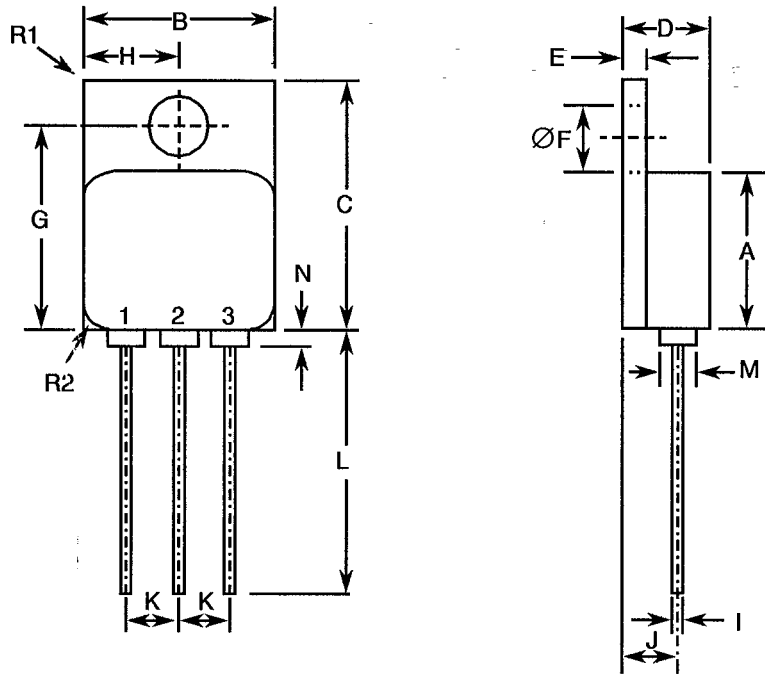
**FIGURE 1 - PARAMETER DERATING INFORMATION**



Average Output Rectified Current versus Temperature



**FIGURE 2 - PHYSICAL DIMENSIONS**



SYMBOL	MILLIMETRES	
	MIN.	MAX.
A	13.59	13.84
B	13.59	13.84
C	20.07	20.32
D	6.3	6.7
E	1.0	1.35
ØF	3.5	3.9
G	16.89	17.4
H	6.86 Typical	
I	0.89	1.14
J	3.81 Typical	
K	3.81 Typical	
L	12.95	14.5
M	3.05 Typical	
N	-	0.71
R1	-	1.0
R2	1.65 Typical	

**NOTES**

1. All terminals are isolated from case.


**FIGURE 3 - FUNCTIONAL DIAGRAM**

Terminal 1: Cathode  
Terminal 2: N.C.  
Terminal 3: Anode



**NOTES**

1. All terminals are isolated from case.

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#### 4. REQUIREMENTS

##### 4.1 GENERAL

The complete requirements for procurement of the diodes specified herein are as stated in this specification and ESCC Generic Specification No. 5000 for Discrete Semiconductors. Deviations from the Generic Specification, applicable to this specification only, are listed in Para. 4.2.

Deviations from the applicable Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESCC requirements and do not affect the components' reliability, are listed in the appendices attached to this specification.

##### 4.2 DEVIATIONS FROM GENERIC SPECIFICATION

###### 4.2.1 Deviations from Special In-process Controls

None.

###### 4.2.2 Deviations from Final Production Tests (Chart II)

None.

###### 4.2.3 Deviations from Burn-in and Electrical Measurements (Chart III)

(a) Para. 9.9.5, Safe Operating Area: Not applicable.

###### 4.2.4 Deviations from Qualification Tests (Chart IV)

(a) Para. 9.15, Constant Acceleration: Not applicable.

###### 4.2.5 Deviations from Lot Acceptance Tests (Chart V)

(a) Para. 9.15, Constant Acceleration: Not applicable.

##### 4.3 MECHANICAL REQUIREMENTS

###### 4.3.1 Dimension Check

The dimensions of the diodes specified herein shall be checked. They shall conform to those shown in Figure 2.

###### 4.3.2 Weight

The maximum weight of the diodes specified herein shall be 10 grammes.

###### 4.3.3 Terminal Strength

The requirements for terminal strength testing are specified in Section 9 of ESCC Generic Specification No. 5000. The test conditions shall be as follows:-

Test Condition: 'A' (Tension).

Applied Force: 10 Newtons.

Duration: 10 seconds.

##### 4.4 MATERIALS AND FINISHES

The materials and finishes shall be as specified herein. Where a definite material is not specified, a material which will enable the diodes specified herein to meet the performance requirements of this specification shall be used. Acceptance or approval of any constituent material does not guarantee acceptance of the finished product.

4.4.1 Case

The case shall be hermetically sealed and have a metal body. The Fe/Ni copper core pin shall pass through a ceramic eyelet brazed into the frame and the lid shall be welded.

4.4.2 Lead Material and Finish

The lead material shall be 'H' with Type '9' finish in accordance with the requirements of ESCC Basic Specification No. 23500. (See Table 1(a) for Type Variants).

4.5 MARKING

4.5.1 General

The marking of all components delivered to this specification shall be in accordance with the requirements of ESCC Basic Specification No. 21700 and the following paragraphs. When the component is too small to accommodate all of the marking specified, as much as space permits shall be marked and the marking information, in full, shall accompany the component in its primary package.

The information to be marked and the order of precedence, shall be as follows:-

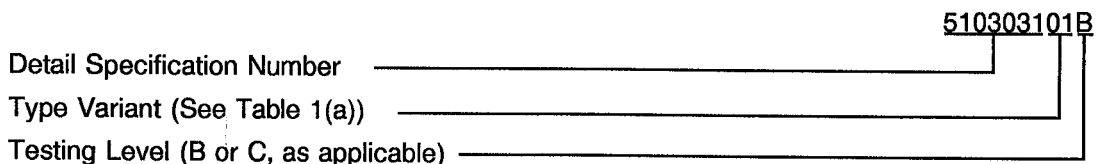
- (a) Terminal Identification.
- (b) The ESCC Component Number.
- (c) Traceability Information.

4.5.2 Terminal Identification

Terminal identification shall be as shown in Figures 2 and 3 of this specification.

4.5.3 The ESCC Component Number

Each component shall bear the ESCC Component Number which shall be constituted and marked as follows:



4.5.4 Traceability Information

Each component shall be marked in respect of traceability information in accordance with the requirements of ESCC Basic Specification No. 21700.


4.6 ELECTRICAL MEASUREMENTS

4.6.1 Electrical Measurements at Room Temperature

The parameters to be measured at room temperature are scheduled in Table 2. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3 \text{ }^\circ\text{C}$ .

4.6.2 Electrical Measurements at High and Low Temperatures

The parameters to be measured at high and low temperatures are scheduled in Table 3. Unless otherwise specified, the measurements in Table 3(a) shall be performed at  $T_{case} = +125 (+0 - 5) \text{ }^\circ\text{C}$  and the measurement in Table 3(b) at  $T_{case} = -55 (+5 - 0) \text{ }^\circ\text{C}$ .

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4.6.3 Circuits for Electrical Measurements (Figure 4)

Not applicable.

4.7 BURN-IN TESTS

4.7.1 Parameter Drift Values

The parameter drift values applicable to burn-in are specified in Table 4 of this specification. Unless otherwise stated, measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C. The parameter drift values ( $\Delta$ ) applicable to the parameters scheduled, shall not be exceeded. In addition to these drift value requirements, the appropriate limit value specified for a given parameter in Table 2 shall not be exceeded.

4.7.2 Conditions for High Temperature Reverse Bias Burn-in

The requirements for high temperature reverse bias burn-in are specified in Section 7 of ESCC Generic Specification No. 5000. The conditions for high temperature reverse bias burn-in shall be as specified in Table 5(a) of this specification.

4.7.3 Conditions for Power Burn-in

The requirements for power burn-in are specified in Section 7 of ESCC Generic Specification No. 5000. The conditions for power burn-in shall be as specified in Table 5(b) of this specification.

4.7.4 Electrical Circuits for High Temperature Reverse Bias Burn-in (Figure 5(a))

Not applicable.

4.7.5 Electrical Circuits for Power Burn-in (Figure 5(b))

Not applicable.



**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - DC PARAMETERS**

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN.	MAX.	
1	Forward Voltage Drop 1	$V_{F1}$	4011	$I_F = 20A$ (Note 1)	-	1.1	V
2	Forward Voltage Drop 2	$V_{F2}$	4011	$I_F = 30A$ (Note 1)	-	1.3	V
3	Reverse Current	$I_R$	4016	DC Method $V_R = V_{RWM} = 200V$	-	50	$\mu A$
4	Breakdown Voltage	$V_{(BR)}$	4021	$I_R = 100\mu A$	200	-	V

**NOTES**

1. Pulsed measurement: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2.0\%$ .

**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - AC PARAMETERS**

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN.	MAX.	
5	Junction Capacitance	$C_J$	4001	$V_R = 10V$ $f = 1.0MHz$	-	400	pF
6	Reverse Recovery Time	$t_{rr}$	4031 Cond. 'B'	$I_F = 1.0A$ $V_R = 30V$ $di_F/dt = -50A/\mu s$	-	60	ns
7	Thermal Impedance (Junction to Case)	$Z_{TH(J-C)}$	3101	$I_H = 15$ to $40A$ $t_H = 50ms$ $I_M = 50mA$ $t_{md} = 100\mu s$ (Note 2)	(Calculate $\Delta V_F$ , see Note 1)		$^{\circ}C/W$

**NOTES**

1. The limits for  $\Delta V_F$  shall be defined by the manufacturer on every lot in accordance with MIL-STD-750 Method 3101, and shall guarantee the  $R_{TH(J-C)}$  limit specified in Table 1(b).
2. During Chart II only, go-no-go.

**TABLE 3(a) - ELECTRICAL MEASUREMENTS AT HIGH TEMPERATURE**

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN.	MAX.	
1	Forward Voltage Drop 1	$V_{F1}$	4011	$I_F = 20A$ $T_{case} = +125^\circ C$ (Note 1)	-	1.0	V
2	Forward Voltage Drop 2	$V_{F2}$	4011	$I_F = 30A$ $T_{case} = +125^\circ C$ (Note 1)	-	1.1	V
3	Reverse Current	$I_R$	4016	$V_R = 200V$ $T_{case} = +125^\circ C$	-	40	mA

**NOTES**

1. Pulsed measurement: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2.0\%$ .

**TABLE 3(b) - ELECTRICAL MEASUREMENTS AT LOW TEMPERATURE**

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN.	MAX.	
1	Forward Voltage Drop 1	$V_{F1}$	4011	$I_F = 20A$ $T_{case} = -55^\circ C$ (Note 1)	-	1.3	V

**NOTES**

1. Pulsed measurement: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2.0\%$ .

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS**

Not applicable.

**TABLE 4 - PARAMETER DRIFT VALUES**

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMIT ( $\Delta$ )	UNIT
1	Forward Voltage Drop 1	$V_{F1}$	As per Table 2	As per Table 2	$\pm 70$	mV
3	Reverse Current	$I_R$	As per Table 2	As per Table 2	$\pm 6.0$ or (1) $\pm 100$	$\mu A$  %

**NOTES**

1. Whichever is greater, referred to the initial value.

**TABLE 5(a) - CONDITIONS FOR HIGH TEMPERATURE REVERSE BIAS BURN-IN**

No.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Ambient Temperature	$T_{amb}$	+ 150	°C
2	Reverse Voltage	$V_R$	160	V
3	Average Output Rectified Current	$I_O$	0	A
4	Duration	t	48	Hrs

**TABLE 5(b) - CONDITIONS FOR POWER BURN-IN AND OPERATING LIFE TESTS**

No.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Case Temperature	$T_{case}$	+ 125 ± 15 (Note 1)	°C
2	Junction Temperature	$T_J$	+ 150 (+ 0-5)	°C
3	Average Output Rectified Current	$I_O$	≥ 10 (Note 1)	A

**NOTES**

1. The case temperature and/or output current may be adjusted, within their given condition ranges, to attain the specified junction temperature.

**FIGURE 5(a) - ELECTRICAL CIRCUIT FOR HIGH TEMPERATURE REVERSE BIAS BURN-IN**

Not applicable.

**FIGURE 5(b) - ELECTRICAL CIRCUIT FOR BURN-IN AND OPERATING LIFE TESTS**

Not applicable.

4.8 ENVIRONMENTAL AND ENDURANCE TESTS (CHARTS IV AND V OF ESCC GENERIC SPECIFICATION NO. 5000)

4.8.1 Electrical Measurements on Completion of Environmental Tests

The parameters to be measured on completion of environmental tests are scheduled in Table 2. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

4.8.2 Electrical Measurements at Intermediate Points and on Completion of Endurance Tests

The parameters to be measured at intermediate points and on completion of endurance tests are scheduled in Table 6 of this specification. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

4.8.3 Conditions for Operating Life Tests (Part of Endurance Testing)

The requirements for operating life testing are specified in Section 9 of ESCC Generic Specification No. 5000. The conditions for operating life testing shall be the same as specified in Table 5(b) for the power burn-in.

4.8.4 Electrical Circuits for Operating Life Tests (Figure 5(b))

Not applicable.


4.8.5 Conditions for High Temperature Storage Test (Part of Endurance Testing)

The requirements for the high temperature storage test are specified in Section 9 of ESCC Generic Specification No. 5000. The temperature to be applied shall be the maximum storage temperature specified in Table 1(b) of this specification.

**TABLE 6 - ELECTRICAL MEASUREMENTS AT INTERMEDIATE POINTS AND ON COMPLETION OF ENDURANCE TESTING**

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN.	MAX.	
1	Forward Voltage Drop 1	$V_{F1}$	As per Table 2	As per Table 2	-	1.0	V
3	Reverse Current	$I_R$	As per Table 2	As per Table 2	-	50	$\mu A$



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**APPENDIX 'A'**

**AGREED DEVIATIONS FOR STMicroelectronics (F)**

ITEMS AFFECTED	DESCRIPTION OF DEVIATIONS
Para. 4.2.2	Para. 9.1 Internal Visual Inspection: Wedge bonds equal to 1.1 wire diameters are acceptable for bonding with V-Groove tool.